

U74CBTLV3251

Advance

LOW-VOLTAGE 1-OF-8 FET MULTIPLEXER/DEMULTIPLEXER

DESCRIPTION

The **U74CBTLV3251** device is a 1-of-8 high-speed FET multiplexer/demultiplexer. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The select inputs (S0, S1, S2) control the data flow. The FET multiplexers/demultiplexers are disabled when the output-enable (\overline{OE}) input is high.

This device is fully specified for partial-power-down applications using I_{OFF} . The I_{OFF} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



FEATURES

* 5 Ω Switch Connection Between Two Ports

- * Rail-to-Rail Switching on Data I/O Ports
- * I_{OFF} Supports Partial-Power-Down Mode Operation

ORDERING INFORMATION

Ordering	Number	Deekege	Decking
Lead Free Halogen Free		Package	Packing
U74CBTLV3251L-R16-R	U74CBTLV3251G-R16-R	SSOP-16	Tape Reel
U74CBTLV3251L-P16-R	U74CBTLV3251G-P16-R	TSSOP-16	Tape Reel

(1) Packing Type (1) R: Tape Reel (2) Package Type (2) R16: SSOP-16, P16: TSSOP-16	U74CBTLV3251G-R16-R		
(2) Package Type (2) R16: SSOP-16, P16: TSSOP-16		(1) Packing Type	(1) R: Tape Reel
		(2) Package Type	(2) R16: SSOP-16, P16: TSSOP-16
(3) Green Package (3) G: Halogen Free and Lead Free, L: Lead Fr		(3) Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



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PIN CONFIGURATION



FUNCTION TABLE (each bus switch)

	INP		FUNCTION	
ŌĒ	S2	S1	S0	FUNCTION
L	L	L	L	A port = B1 port
L	L	L	Н	A port = B2 port
L	L	Н	L	A port = B3 port
L	L	Н	Н	A port = B4 port
L	Н	L	L	A port = B5 port
L	Н	L	Н	A port = B6 port
L	Н	Н	L	A port = B7 port
L	Н	Н	Н	A port = B8 port
Н	х	Х	Х	Disconnect



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■ LOGIC DIAGRAM (positive logic)



■ SIMPLIFIED SCHEMATIC (each FET switch)





■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V _{CC}		-0.5 ~ 4.6	V
Input Voltage	V _{IN}		-0.5 ~ 4.6	V
Continuous Channel Through V _{CC} or GND			128	mA
Input Clamp Current	I _{IK}	V _{I0} <0	-50	mA
Storage Temperature Range	T _{STG}		-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SSOP-16	0	90	°C/W
	TSSOP-16	θ _{JA}	115	°C/W

RECOMMENDED OPERATING COMDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	Vcc		2.3		3.6	V
		V _{CC} =2.3V~2.7V	1.7			N
High-control input voltage	VIH	V _{CC} =2.7V~3.6V	2			V
	N	V _{CC} =2.3V~2.7V			0.7	V
Low-control input voltage	VIL	V _{CC} =2.7V~3.6V			0.8	V
Operating Temperature	T _A		-40		+125	°C

Note: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

■ ELECTRICAL CHARACTERISTICS (unless otherwise specified)

PARAMETER			тго			Т		0	T _A =-40°C~+125°C			UNIT
PARAMEI	ER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
Digital Input Diode	e Voltage	VIK	V _{CC} =3V,	V _{CC} =3V, I _I =-18mA				-1.2			-1.2	V
Input Leakage Cu	rrent	l _l	V _{CC} =3.6V	, V _I =V _{CC} o	r GND			±1			±20	μA
Power off Leakag	e Current	I _{OFF}	V _{CC} =0, V _I	or V _O =0 to	o 3.6V			±20			±50	μA
Quiescent Supply	Current	Icc	$V_{CC}=3.6V$, $V_{I}=V_{CC}$ or GND, $I_{O}=0$				10			50	μA	
Additional Quiescent Supply Current (Note 1)	Control Inputs		V _{CC} =3.6V, One input at 3V, Other inputs at V _{CC} or GND					300			2000	μΑ
			V _{CC} =2.3V	V-0	l₁=64mA		5	8			15	Ω
	4		TYP at	V _{CC} =2.3V TYP at V _I =0 <u>I_I=64mA</u>			5	8			15	Ω
Resistor between	two	Б	V _{CC} =2.5V V _I =1.7V I _I =		l _I =-15mA		27	40			60	Ω
ports (Note 2)		R _{ON}			l₁=64mA		5	7			11	Ω
			V _{CC} =3V	V _{CC} =3V V _I =0V			5	7			11	Ω
				V _I =2.4V	l _I =-15mA		10	15			26	Ω

Notes: 1. This is the increase in supply current for each input that is at the specified voltage level, rather than V_{CC} or GND.

2. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.



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SWITCHING CHARACTERISTICS

See Fig. 1 and Fig. 2 for test circuit and waveforms.

			Т	T _A =25°C			T _A =-40°C~+125°C			
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
Propagation Delay From		V _{CC} =2.5V±0.2V			0.15			0.3	ns	
Input (A or B) (Note) to Output (B or A)	t _{pd}	V _{CC} =3.3V±0.3V			0.25			0.5	ns	
Propagation Delay From	,	V _{CC} =2.5V±0.2V	1		6.1			8.1	ns	
Input (S) to Output (A)		V _{CC} =3.3V±0.3V	1		5.3			7.3	ns	
Propagation Delay From	F	$V_{CC}=2.5V\pm0.2V$	1		5.4			7.4	ns	
Input (S) to Output (B)		V _{CC} =3.3V±0.3V	1		4.8			6.8	ns	
Propagation Delay From	(t _{PZL} /t _{PZH})	V _{CC} =2.5V±0.2V	1		5.2			7.2	ns	
Input (\overline{OE}) to Output (A or B)	(*FZL/*FZN)	V _{CC} =3.3V±0.3V	1		4.5			6.5	ns	
Propagation Delay From		V _{CC} =2.5V±0.2V	1		4.8			6.8	ns	
Input (S) to Output (B)	t.e.	V _{CC} =3.3V±0.3V	1		4.5			6.5	ns	
Propagation Delay From	m $\frac{t_{dis}}{(t_{PLZ}/t_{PHZ})}$	V _{CC} =2.5V±0.2V	1		6.7			8.2	ns	
Input (\overline{OE}) to Output (A or B)	(*PLZ/*PNZ)	V _{CC} =3.3V±0.3V	1		7.2			8.8	ns	

Note: The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

■ **OPERATING CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAME1	ER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Control input Capacitance	Control Inputs	Cı	V ₀ =3V or 0		3		pF
I/O Capacitance	A Port	0	$\sqrt{-2}$		40.5		pF
(OFF)	B Port	CIO(OFF)	$V_0=3V \text{ or } 0, \text{ OE}=V_{CC}$		6		рF



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- Notes: 1. C_L includes probe and jig capacitance.
 - 2. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

- 3. All input pulses are supplied by generators having the following characteristics:
- $P_{RR} \le 10MHz$, $Z_0=50\Omega$, $t_r \le 2ns$, $t_f \le 2ns$.
- 4. t_{PLZ} and t_{PHZ} are the same as $t_{\mathsf{dis}}.$
- 5. t_{PZL} and t_{PZH} are the same as t_{en} .
- 6. t_{PLH} and t_{PHL} are the same as $t_{\mathsf{pd}}.$

Load circuitry and voltage waveforms



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